

TLP797J

TELECOMMUNICATION

MEASUREMENT EQUIPMENT

FA

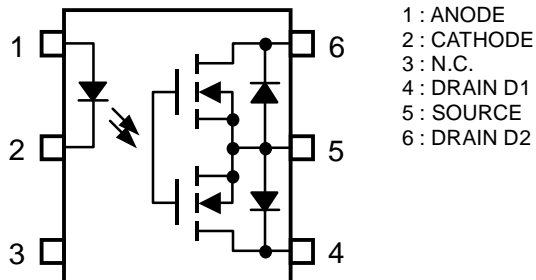
The TOSHIBA TLP797J consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in a six lead plastic DIP package (DIP6).

The TLP797J is a bi-directional switch can replace mechanical relays in many applications.

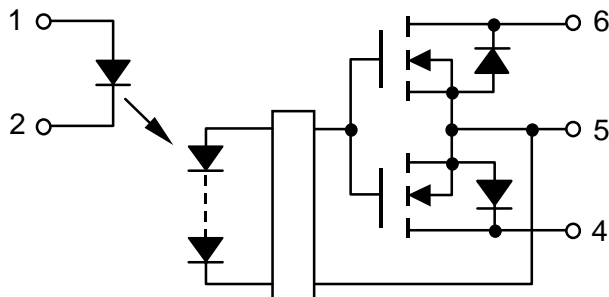
FEATURES

- 6 pin DIP (DIP6)
- 1-Form-A
- Peak Off-State Voltage : 600 V (MIN.)
- Trigger LED Current : 5mA (MAX.)
- On-State Current : 100 mA (MAX.)
- On-State Resistance : 35 Ω (MAX.)
- Isolation Voltage : 5000 Vrms (MIN.)

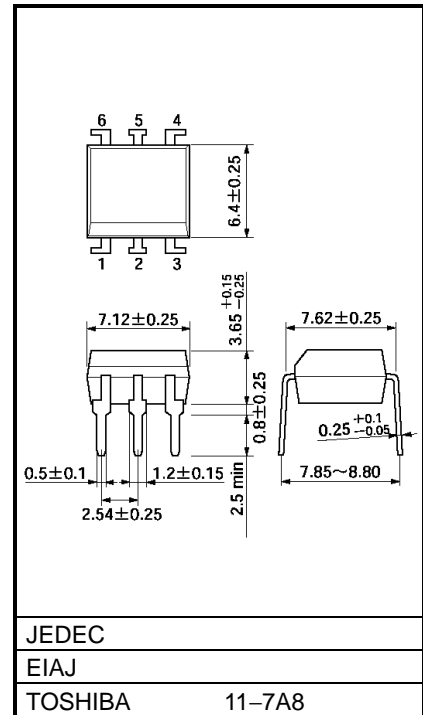
PIN CONFIGURATION (TOL VIEW)



SCHEMATIC



Unit: mm



Weight: 0.4 g

MAXIMUM RATINGS (Ta = 25°C)

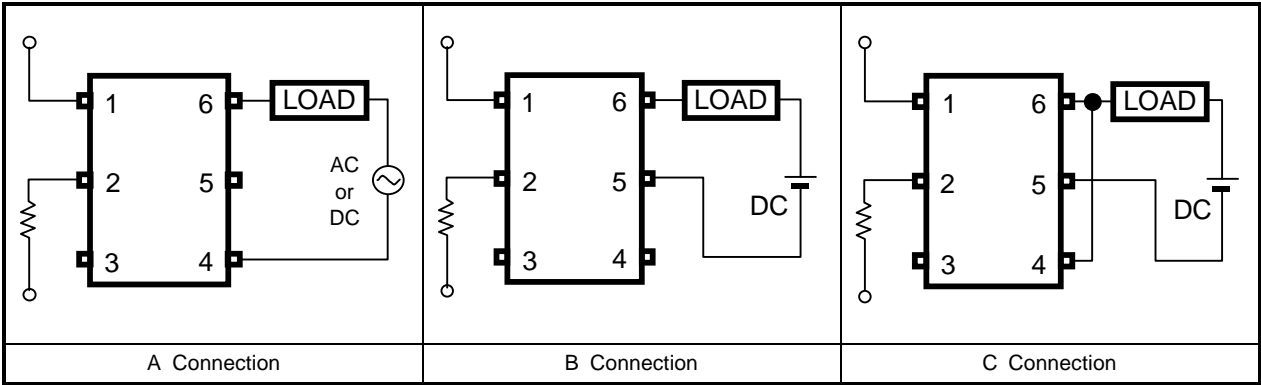
| CHARACTERISTIC | | | SYMBOL | RATING | UNIT |
|--|--|------------------|----------------------|--------|------------------|
| LED | Forward Current | | I _F | 50 | mA |
| | Forward Current Derating (T _a ≥ 25°C) | | ΔI _F /°C | −0.5 | mA/°C |
| | Peak Forward Current (100 μs pulse, 100 pps) | | I _{FP} | 1 | A |
| | Reverse Voltage | | V _R | 5 | V |
| | Junction Temperature | | T _j | 125 | °C |
| DETECTOR | Off-State Output Terminal Voltage | | V _{OFF} | 600 | V |
| | On-State Current | A Connection | I _{ON} | 100 | mA |
| | | B Connection | | 100 | |
| | | C Connection | | 200 | |
| | On-State Current Derating (T _a ≥ 25°C) | A Connection | ΔI _{ON} /°C | −1.0 | mA/°C |
| | | B Connection | | −1.0 | |
| | | C Connection | | −2.0 | |
| | Junction Temperature | | T _j | 125 | °C |
| Storage Temperature Range | | T _{stg} | −55~125 | °C | |
| Operating Temperature Range | | T _{opr} | −40~85 | °C | |
| Lead Soldering Temperature (10 s) | | T _{sol} | 260 | °C | |
| Isolation Voltage (AC, 1 minute, R.H. ≤ 60%) (NOTE1) | | | BV _S | 5000 | V _{rms} |

(NOTE1) : Device considered a two-terminal device : Pins 1, 2 and 3 shorted together, and pins 4, 5 and 6 shorted together.

RECOMMENDED OPERATING CONDITIONS

| CHARACTERISTIC | SYMBOL | MIN. | TYP. | MAX. | UNIT |
|-----------------------|--------|------|------|------|------|
| Supply Voltage | VDD | — | — | 480 | V |
| Forward Current | IF | 7.5 | 15 | 25 | mA |
| On-State Current | ION | — | — | 100 | mA |
| Operating Temperature | Topr | −20 | — | 65 | °C |

CIRCUIT CONNECTIONS



INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

| CHARACTERISTIC | | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|----------------|-------------------|-----------|----------------------------|------|------|------|---------------|
| LED | Forward Voltage | V_F | $I_F = 10 \text{ mA}$ | 1.0 | 1.15 | 1.3 | V |
| | Reverse Current | I_R | $V_R = 5 \text{ V}$ | — | — | 10 | μA |
| | Capacitance | C_T | $V = 0, f = 1 \text{ MHz}$ | — | 30 | — | pF |
| DETECTOR | Off-State Current | I_{OFF} | $V_{OFF} = 600 \text{ V}$ | — | — | 1 | μA |
| | Capacitance | C_{OFF} | $V = 0, f = 1 \text{ MHz}$ | — | 120 | — | pF |

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

| CHARACTERISTIC | | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|---------------------|--------------|----------|---|------|------|------|----------|
| Trigger LED Current | | I_{FT} | $I_{ON} = 100 \text{ mA}$ | — | 1.6 | 5 | mA |
| Return LED Current | | I_{FC} | $I_{OFF} = 100 \mu\text{A}$ | 0.1 | — | — | mA |
| On-State Resistance | A Connection | R_{ON} | $I_{ON} = 100 \text{ mA}, I_F = 10 \text{ mA}, t < 1 \text{ s}$ | — | 25 | 35 | Ω |
| | | | $I_{ON} = 100 \text{ mA}, I_F = 10 \text{ mA}$ | — | 30 | 45 | |
| | B Connection | | $I_{ON} = 100 \text{ mA}, I_F = 10 \text{ mA}$ | — | 23 | 35 | |
| | C Connection | | $I_{ON} = 200 \text{ mA}, I_F = 10 \text{ mA}$ | — | 12 | — | |

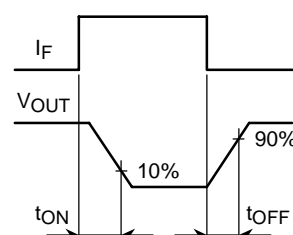
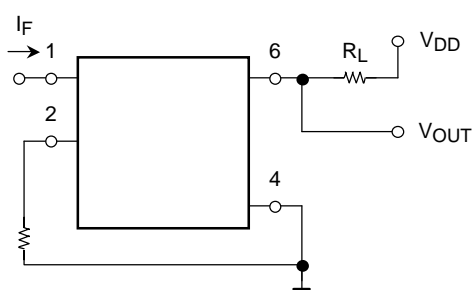
ISOLATION CHARACTERISTICS (Ta = 25°C)

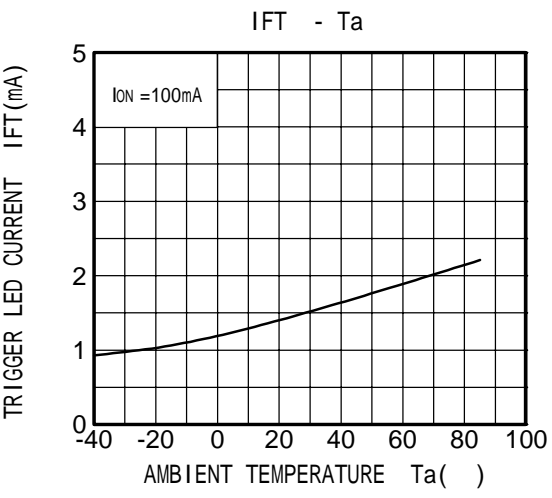
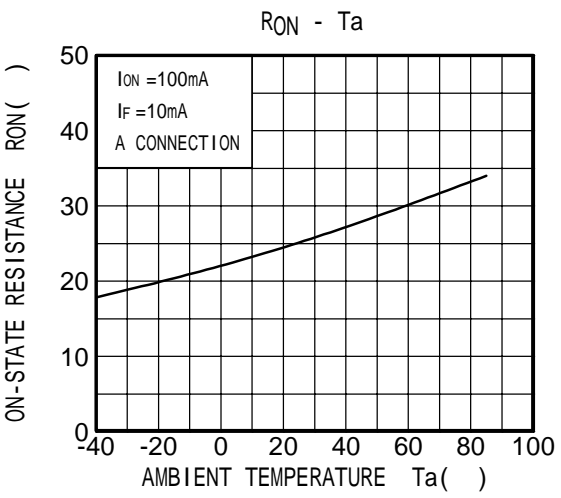
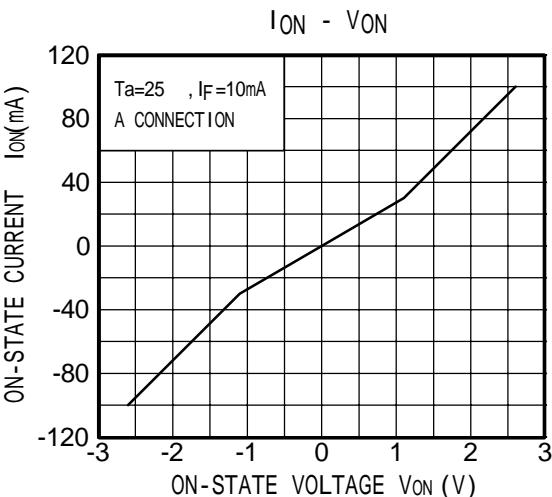
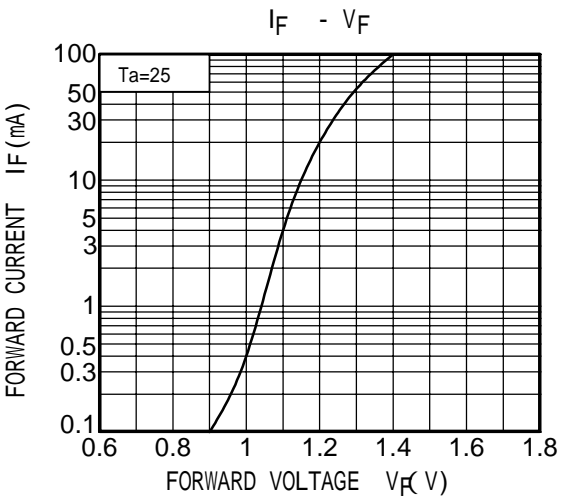
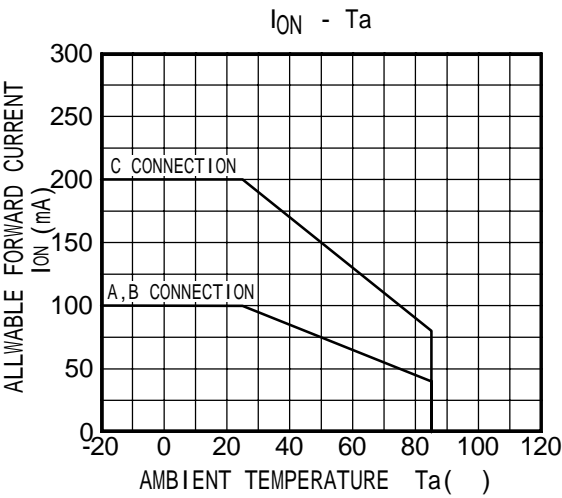
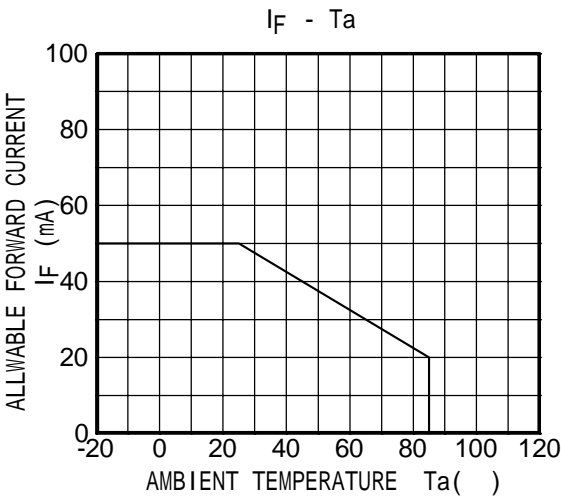
| CHARACTERISTIC | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|-----------------------------|--------|--|--------------------|-----------|------|-----------|
| Capacitance Input to Output | C_S | $V_S = 0 \text{ V}, f = 1 \text{ MHz}$ | — | 0.8 | — | pF |
| Isolation Resistance | R_S | $V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$ | 5×10^{10} | 10^{14} | — | Ω |
| Isolation Voltage | BV_S | AC, 1 minute | 5000 | — | — | V_{rms} |
| | | AC, 1 second (in oil) | — | 10000 | — | |
| | | DC, 1 minute (in oil) | — | 10000 | — | Vdc |

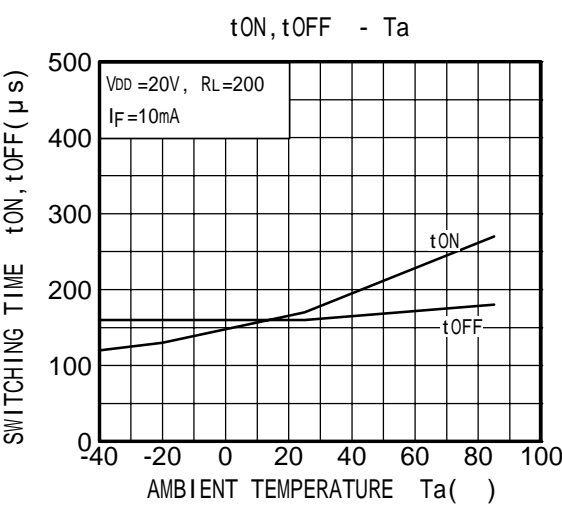
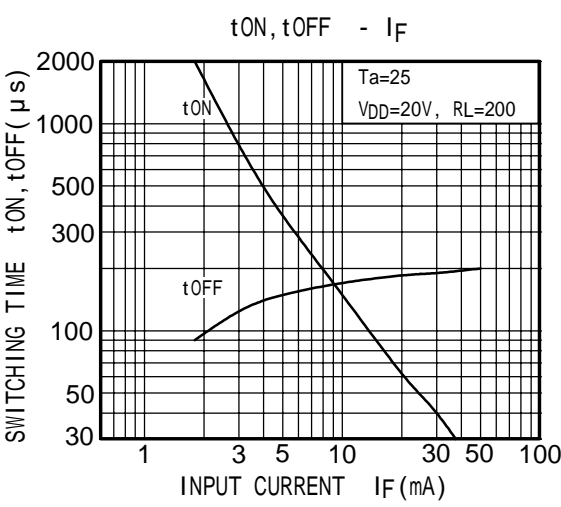
SWITCHING CHARACTERISTICS (Ta = 25°C)

| CHARACTERISTIC | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|----------------|-----------|---|------|------|------|------|
| Turn-on Time | t_{ON} | $R_L = 200 \Omega$ (NOTE 2) $V_{DD} = 20 \text{ V}, I_F = 10 \text{ mA}$ | — | 0.2 | 1.5 | ms |
| Turn-off Time | t_{OFF} | | — | 0.2 | 1 | |

(NOTE 2) : SWITCHING TIME TEST CIRCUIT







RESTRICTIONS ON PRODUCT USE

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